

SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL03C010BA3GNNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 1pF, 25V, ±0.1pF, C0G, 0201

A. Samsung Part Number

<u>CL</u> <u>03</u> <u>C</u> <u>010</u> <u>B</u> <u>A</u> <u>3</u> <u>G</u> <u>N</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor			
2	Size	0201 (inch code)) L: 0.6	± 0.03 mm	W: $0.3 \pm 0.03 \text{ mm}$
	Dialogatuia	000		lunas alaatsada	Cu
3	Dielectric	C0G	(8)	Inner electrode	Cu
4	Capacitance	1 pF		Termination	Cu
(5)	Capacitance	±0.1 pF		Plating	Sn 100% (Pb Free)
	tolerance		9	Product	Normal
6	Rated Voltage	25 V	10	Special	Reserved for future use
7	Thickness	0.3 ± 0.03 mi	m (1)	Packaging	Cardboard Type, 7" reel

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition			
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms			
Q	420 min				
Insulation 10,000Mohm or 500Mohm⋅μF		Rated Voltage 60~120 sec.			
Resistance	Whichever is Smaller				
Appearance	No abnormal exterior appearance	Microscope (×10)			
Withstanding	No dielectric breakdown or	300% of the rated voltage			
Voltage	mechanical breakdown				
Temperature	COG				
Characterisitcs	(From -55 ℃ to 125 ℃, Capacitance change shoud be within ±30PPM/℃)				
Adhesive Strength	No peeling shall be occur on the	200g·F, for 10±1 sec.			
of Termination	terminal electrode				
Bending Strength	Capacitance change :	Bending to the limit (1mm)			
	within ±5% or ±0.5pF whichever is larger	with 1.0mm/sec.			
Solderability	More than 75% of terminal surface	1) Sn63Pb37 solder			
	is to be soldered newly	235±5℃, 5±0.5sec.			
		2) SnAg3.0Cu0.5 solder			
		245±5℃, 3±0.3sec.			
		(preheating : 80~120℃ for 10~30sec.)			
Resistance to	Capacitance change :	Solder pot : 270±5℃, 10±1sec.			
Soldering heat	within ±2.5% or ±0.25pF whichever is larger				
	Tan δ, IR : initial spec.				

	Performance	Test condition
Vibration Test	Capacitance change :	Amplitude : 1.5mm
	within ±2.5% or ±0.25pF whichever is larger	From 10Hz to 55Hz (return : 1min.)
	Tan δ, IR : initial spec.	2hours × 3 direction (x, y, z)
Humidity	Capacitance change :	40±2℃, 90~95%RH, 500+12/-0hrs
	within ±5% or ±0.5pF whichever is larger	
Q: 210 min		
	IR: 1000Mohm or 50Mohm · μF	
Whichever is Smaller		
Moisture	Capacitance change :	With rated voltage
Resistance	within ±7.5% or ±0.75pF whichever is larger	40±2℃, 90~95%RH, 500+12/-0hrs
	Q: 103.33 min	
	IR: 500Mohm or 25Mohm · μF	
	Whichever is Smaller	
High Temperature	Capacitance change :	With 200% of the rated voltage
Resistance	within ±3% or ±0.3pF whichever is larger	Max. operating temperature
	Q: 210 min	1000+48/-0hrs
	IR : 1000Mohm or 50Mohm · μF	
	Whichever is Smaller	
Temperature	Capacitance change :	1 cycle condition
Cycling	within ±2.5% or ±0.25pF whichever is larger	Min. operating temperatur → 25 °C
	Tan δ, IR : initial spec.	→ Max. operating temperature → 25°C
		5 cycle test

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}\!\!\mathrm{C}$, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.